

## Features

- Solid-state silicon-avalanche technology
- Low operating and clamping voltage
- Up to four I/O Lines of Protection
- Ultra low capacitance: 0.35pF typical(I/O to I/O)
- Low Leakage
- Low operating voltage:5V
- Flow-Through design



## IEC COMPATIBILITY (EN61000-4)

- IEC 61000-4-2 (ESD)  $\pm 15\text{kV}$  (air),  $\pm 8\text{kV}$  (contact)
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 5A (8/20 $\mu\text{s}$ )

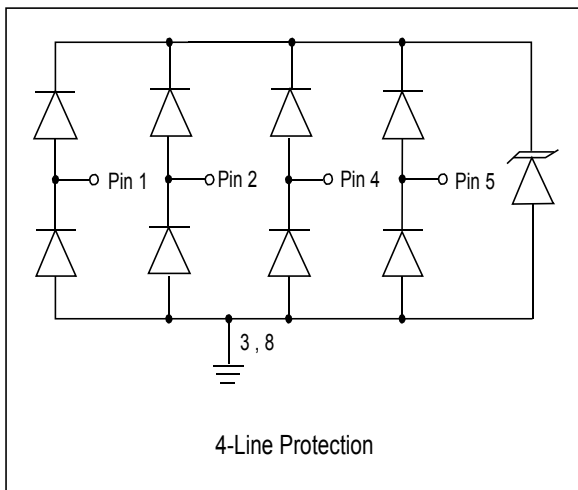
## Mechanical Characteristics

- DFN-10L package (2.5×1.0×0.58mm)
- Molding compound flammability rating: UL 94V-0
- Marking: Marking Code
- Packaging: Tape and Reel
- RoHS/WEEE Compliant

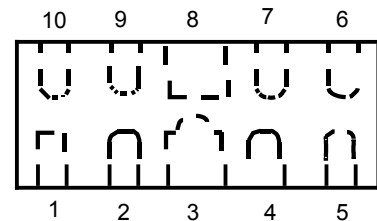
## Applications

- Digital Visual Interface(DVI)
- MDDI Ports
- DisplayPort™ Interface
- PCI Express
- High Definition Multi-Media Interface(HDMI)
- eSATA Interfaces

## Circuit Diagram



## Schematic & PIN Configuration



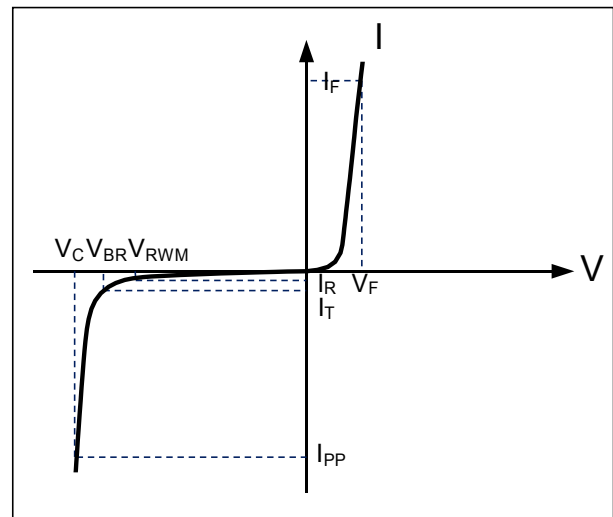
Pin	Identificaion
1,2,4,5	Input Lines
6,7,9,10	Output Lines (No Internal Connection)
3,8	Ground

## Absolute Maximum Rating

Rating	Symbol	Value	Units
Peak Pulse Power ( $t_p=8/20\mu s$ )	$P_{PP}$	150	Watts
Peak Pulse Current ( $t_p=8/20\mu s$ )	$I_{pp}$	5	A
ESD per IEC 61000-4-2(Air)	$V_{ESD}$	+/-17	kV
ESD per IEC 61000-4-2(contact)		+/-12	
Operating Temperature	$T_J$	-55 to + 125	°C
Storage Temperature	$T_{STG}$	-55 to +150	°C

## Electrical Parameters (T=25°C)

Symbol	Parameter
$I_{PP}$	Maximum Reverse Peak Pulse Current
$V_C$	Clamping Voltage @ $I_{PP}$
$V_{RWM}$	Working Peak Reverse Voltage
$I_R$	Maximum Reverse Leakage Current @ $V_{RWM}$
$V_{BR}$	Breakdown Voltage @ $I_T$
$I_T$	Test Current
$I_F$	Forward Current
$V_F$	Forward Voltage @ $I_F$

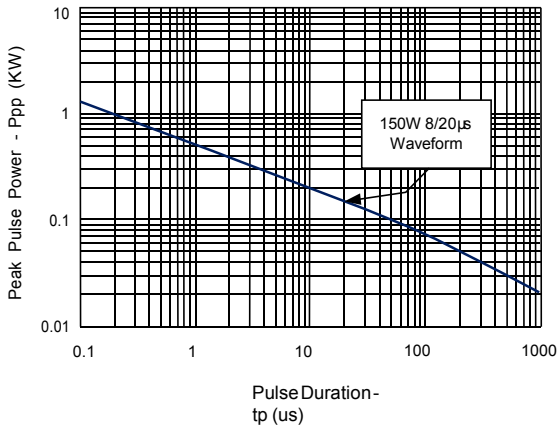


## Electrical Characteristics

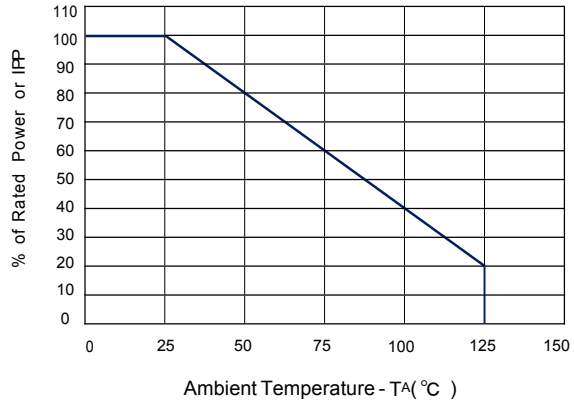
Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand-Off Voltage	$V_{RWM}$	Any I/O pin to ground			5.0	V
Reverse Breakdown Voltage	$V_{BR}$	$I_T = 1mA$ Any I/O pin to ground	6.0			V
Reverse Leakage Current	$I_R$	$V_{RWM} = 5V, T=25^\circ C$ Any I/O pin to ground			1	$\mu A$
Clamping Voltage	$V_C$	$I_{pp}=5A, t_p=8/20\mu s$ Any I/O pin to ground			15	V
Junction Capacitance	$C_j$	$V_R = 0V, f = 1MHz$ I/O pin to GND			0.8	pF
		$V_R = 0V, f = 1MHz$ Between I/O pins		0.3	0.35	pF

# Typical Characteristics

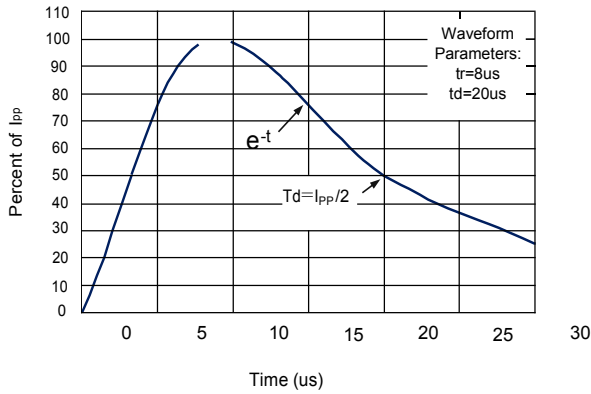
**Non-Repetitive Peak Pulse Power vs. Pulse Time**



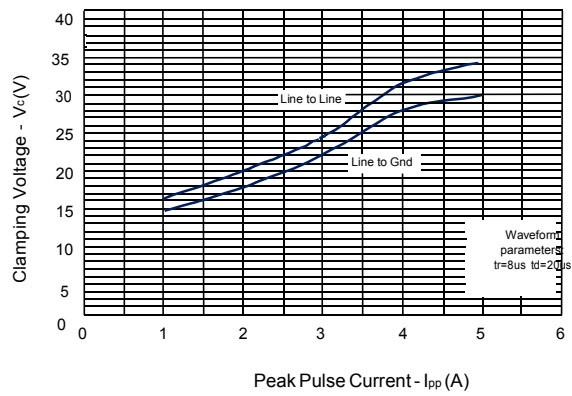
**Power Derating curve**



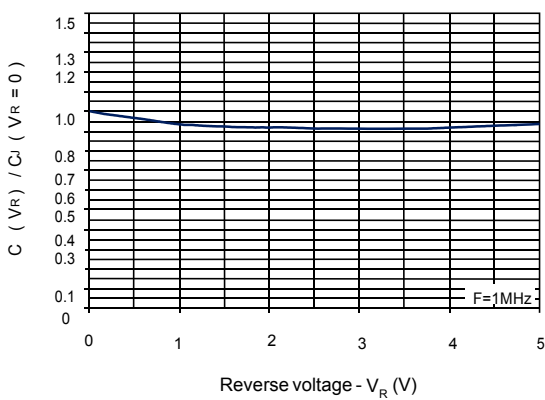
**Pulse Waveform**



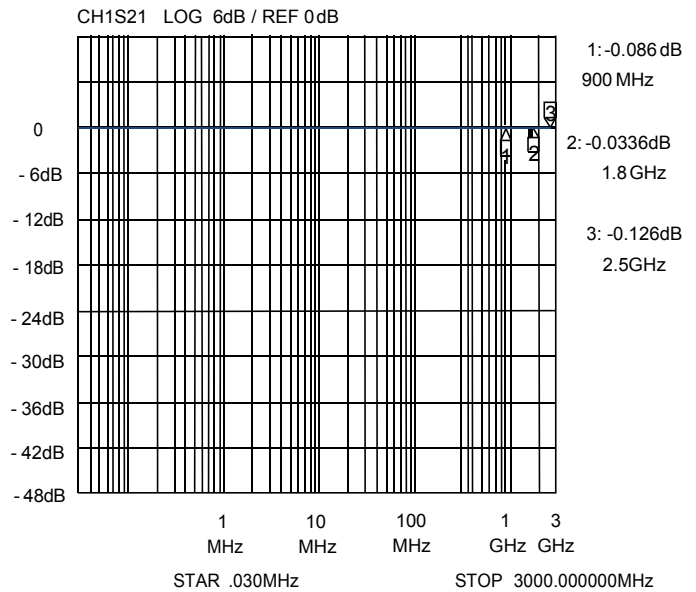
**Clamping Voltage vs. Peak Pulse Current**



**Normalized Capacitance vs. Reverse Voltage**



**Insertion Loss S21 - I/O to GND**



## Design Recommendations for HDMI protection

Adding external ESD protection to HDMI ports can be challenging. First, ESD protection devices have an inherent junction capacitance. Furthermore, adding even a small amount of capacitance will cause the impedance of the differential pair to drop. Second, large packages and land pattern requirements cause discontinuities that adversely affect signal integrity. The BDFN10A054U are specifically designed for protection of high-speed interfaces such as HDMI.

They present <0.4pF capacitance between the pairs while being rated to handle ±8kV ESD contact discharges (±15kV air discharge) as outlined in IEC 61000-4-2. Each device is in a leadless SLP package that is less than 1.1mm wide. They are designed such that the traces flow straight through the device. The narrow package and flow-through design reduces discontinuities and minimizes impact on signal integrity. This becomes even more critical as signal speeds increase.

## Pin Configuration

Figure 1 is an example of how to route the high speed differential traces through the BDFN10A054U. The solid line represents the PCB trace. The PCB traces are used to connect the pin pairs for each line (pin 1 to pin 10, pin 2 to pin 9, pin 4 to pin 7, pin 5 to pin 6). For example, line 1 enters at pin 1 and exits at Pin 10 and the PCB trace connects pin 1 and 10 together. This is true for lines connected at pins 2, 4, and 5 also. Ground is connected at pins 3 and 8. One large ground pad should be used in lieu of two separate pads. The same layout rules apply for the BDFN10A054U

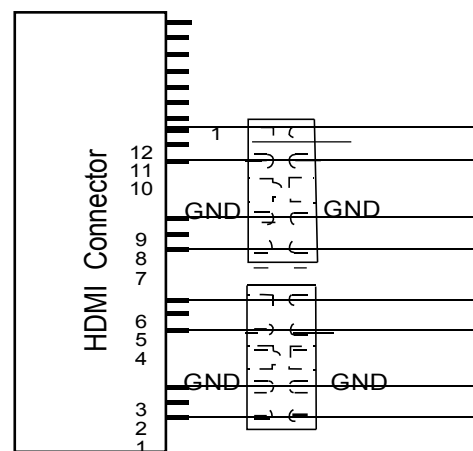


Figure 1. Flow through layout Using BDFN10A054U

## Design Recommendations for HDMI Protection

Good circuit board layout is critical not only for signal integrity, but also for effective suppression of ESD induced transients.

For optimum ESD protection, the following guidelines are recommended:

- Place the device as close to the connector as possible. This practice restricts ESD coupling into adjacent traces and reduces parasitic inductance.
- The ESD transient return path to ground should be kept as short as possible. Whenever possible, use multiple micro vias connected directly from the device ground pad to the ground plane.
- Avoid running critical signals near board edges.

**Outline Drawing – DFN-2L**

**NOTES:**  
1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).

**DFN2.5x1-10L**

DIM	INCHES			MILLIMETERS		
	MIN	NOM	MAX	MIN	NOM	MAX
A	.020	.023	.026	0.50	0.58	0.65
A1	0.00	.001	.002	0.00	0.03	0.05
A2	(0.005)			(0.13)		
b	.006	.008	.010	0.15	0.20	0.25
b1	.014	.016	.018	0.35	0.40	0.45
D	.094	.098	.102	2.40	2.50	2.60
E	.035	.039	.043	0.90	1.00	1.10
e	.020 BSC			0.50 BSC		
L	.012	.015	.017	0.30	0.38	0.425
N	8			8		
aaa	0.003			0.08		
bbb	0.004			0.10		

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DIMENSIONS		
DIM	INCHES	MILLIMETERS
C	(.034)	(0.875)
G	.008	0.20
P	.020	0.50
P1	.039	1.00
X	.008	0.20
X1	.016	0.40
Y	.027	0.675
Y1	(.061)	(1.55)
Z	.061	1.55

**NOTES:**  
1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).  
2. THIS LAND PATTERN IS FOR REFERENCE PURPOSES ONLY.  
CONSULT YOUR MANUFACTURING TO ENSURE YOUR COMPANY'S MANUFACTURING GUIDELINES ARE MET.

**Marking Codes**

Part Number	Marking Code
BDFN10A054U	05 24P

**Package Information**

Qty: 3k/Reel